TOSHIBA BiCD Integrated Circuit Silicon Monolithic

TBD62384APG, TBD62384AFWG

8-ch low active sink type DMOS transistor array

TBD62384A series are DMOS transistor arrays with 8 circuits. Please be careful about thermal conditions during use.

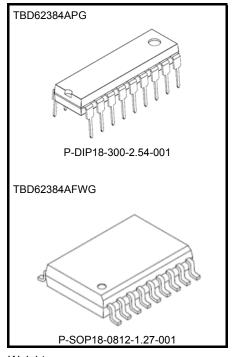
Features

· Built-in 8 circuits

High voltage : V_{OUT} = 50 V (max)
 High current : I_{OUT} = 500 mA/ch (max)
 Input voltage (output on) : -20 V to V_{CC}-3.5 V
 Input voltage (output off) : V_{CC}-0.4 V to V_{CC}

Package : PG type P-DIP18-300-2.54-001

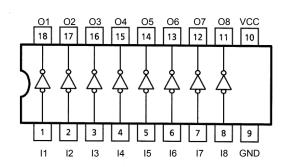
FWG type P-SOP18-0812-1.27-001



Weight

P-DIP18-300-2.54-001 : 1.3 g (typ.) P-SOP18-0812-1.27-001 : 0.5 g (typ.)

Pin Assignment (top view)

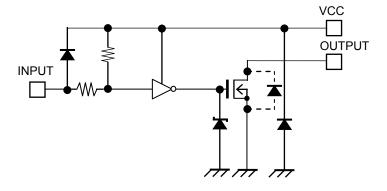


Pin connection may be omitted partially or simplified for explanatory purpose.

Pin Descriptions

Pin No.	Pin name	Function
1	I1	Input pin
2	12	Input pin
3	13	Input pin
4	14	Input pin
5	15	Input pin
6	16	Input pin
7	17	Input pin
8	18	Input pin
9	GND	Ground pin
10	VCC	Power supply pin
11	O8	Output pin
12	07	Output pin
13	O6	Output pin
14	O5	Output pin
15	O4	Output pin
16	O3	Output pin
17	O2	Output pin
18	01	Output pin

Basic Circuit



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Basic circuit may be omitted partially or simplified for explanatory purpose.



Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Power supply voltage		V _{CC}	−0.5 to 6.0	V	
Output voltage		V _{OUT}	50	V	
Output current (per ch)		I _{OUT}	500	mA	
Input voltage		V _{IN}	-22 to V _{CC} +0.5 (Note3)		
Power dissipation	PG (Note1)	В	1.47	W	
	FWG (Note2)	P _D	1.31		
Operating temperature		T _{opr}	-40 to 85	°C	
Storage temperature		T _{stg}	−55 to 150	°C	

Note1: Stand alone When Ta exceeds 25 °C, it is necessary to do the derating with 11.8 mW/°C.

Note2: On PCB (size: 75 mm × 114 mm × 1.6 mm, Cu area: 20 %, single-side glass epoxy) when Ta exceeds 25 °C, it is necessary to do the derating with 10.48 mW/°C.

Note3: Do not exceed 6 V.

Operating Ranges (Ta = -40 to 85° C, unless otherwise specified.)

Character	Symbol	Test c	Min	Тур.	Max	Unit		
Power supply	V _{CC}	_		4.5	5.0	5.5	V	
Output vo	V _{OUT}	_		_	_	50	V	
		- I _{OUT}	1 circuit ON, Ta = 25 °C		0	_	400	
	PG (Note1)		t_{pw} = 25 ms 8 circuits ON Ta = 85 °C T _j = 120 °C	Duty = 10 %	0	_	390	mA
Output current	(1.6.6.1)			Duty = 50 %	0	_	170	
(per ch)	FWG (Note2)		1 circuit ON, Ta = 25 °C		0	_	400	IIIA
			t_{pw} = 25 ms 8 circuits ON Ta = 85 °C T _j = 120 °C	Duty = 10 %	0	_	370	
				Duty = 50 %	0	ı	160	
Input voltage (0	V _{IN (ON)}	I _{OUT} = 100 mA or more, V _{OUT} = 2 V		-20	_	V _{CC} -3.5	٧	
Input voltage (0	V _{IN (OFF)}	I_{OUT} = 100 μ A or	V _{CC} -0.4	_	V _{CC}	V		

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Note1: Stand alone

Note2: On PCB (size: 75 mm × 114 mm × 1.6 mm, Cu area: 20 %, single-side glass epoxy)

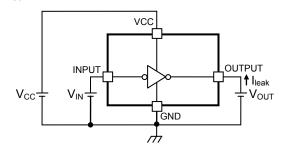


Electrical Characteristics (Ta = 25°C, unless otherwise specified.)

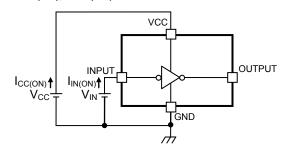
Characteristics	Symbol	Test Circuit	Test conditions	Min	Тур.	Max	Unit
Output leakage current	I _{leak}	1	V _{OUT} = 50 V, Ta = 85 °C V _{IN} = V _{CC} = 5.5 V	_	_	1.0	μА
		2	I _{OUT} = 350 mA V _{CC} = 5.0 V, V _{IN} = 0 V	_	0.525 (1.5)	1.14 (3.25)	V (Ω)
Output voltage (Output ON-resistance)	V _{DS} (R _{ON)}		I _{OUT} = 200 mA, V _{CC} = 5.0 V, V _{IN} = 0 V		0.3 (1.5)	0.65 (3.25)	
			I _{OUT} = 100 mA V _{CC} = 5.0 V, V _{IN} = 0 V	_	0.15 (1.5)	0.325 (3.25)	
		3	V _{CC} = 5.5 V, V _{IN} = 0 V	_	-10	-100	μА
Input current	I _{IN(ON)}		$V_{CC} = 5.5 \text{ V}, V_{IN} = -20 \text{ V}$	_	-100	-200	
	I _{IN(OFF)}	4	V _{CC} = V _{IN} = 5.5 V	_	_	1.0	μА
Consumption current (per ch)	I _{CC(ON)}	3	V _{CC} = 5.5 V, V _{IN} = 0 V	_	70	200	μА
Consumption current (per cir)	I _{CC(OFF)}	4	V_{CC} = 5.5 V, V_{IN} = V_{CC}	_	_	1.0	μΑ
Turn-on delay	t _{ON} 5	_	$V_{CC} = 5.0 \text{ V}, V_{OUT} = 50 \text{ V}$	_	0.6	_	
Turn-off delay		5	$R_L = 125 \Omega$ $C_L = 15 pF$	_	0.6	_	μS

Test Circuit

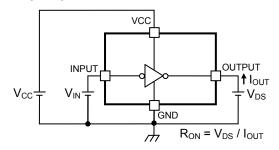
1. I_{leak}



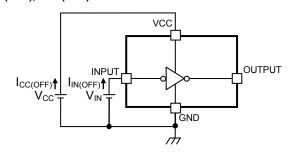
3. $I_{IN (ON)}$, $I_{CC (ON)}$



2. $V_{DS}(R_{ON})$

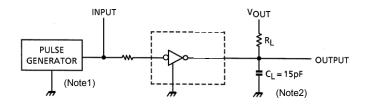


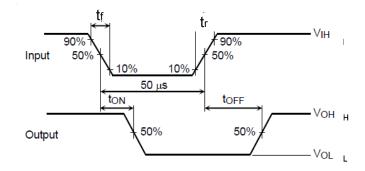
4. $I_{IN (OFF)}$, $I_{CC (OFF)}$



Test circuits may be omitted partially or simplified for explanatory purpose.

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Note1: Pulse width 50 μ s, Duty cycle 10 %

Output impedance 50 Ω , tr \leq 5 ns, tf \leq 10 ns, V_{IH} = 5.0 V

Note2: C_L includes capacitance of the probe and the test board.

Test circuits and timing charts may be omitted partially or simplified for explanatory purpose.

Precautions for Using

This IC does not incorporate built-in protection circuits for excess current or over voltage.

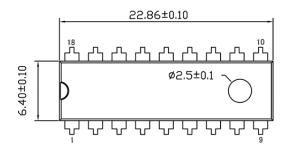
Therefore, if the short-circuit between adjacent pins or between outputs, the short-to-power or ground fault has occurred, the current or voltage beyond the absolute maximum rating is impressed, and IC may be destroyed. When designing, please consider enough in power supply line, output line, and GND line.

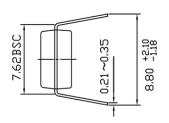
In addition, so as not to continue to flow a current that exceeds the absolute maximum rating of the IC, please insert the appropriate fuse in the power supply line.

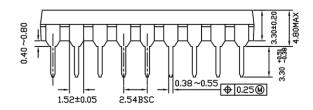
Package Dimensions

P-DIP18-300-2.54-001





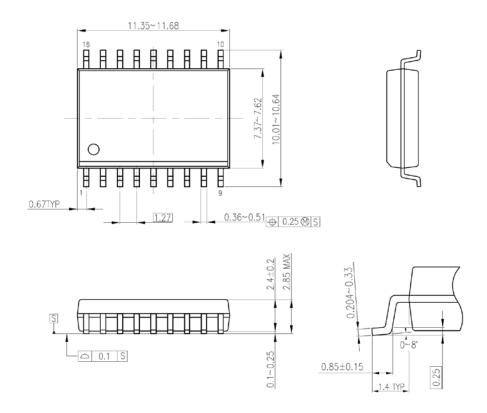




Weight: 1.3 g (typ.)

P-SOP18-0812-1.27-001

Unit: mm



Weight: 0.5 g (typ.)

Notes on Contents

1. Pin Connection

Pin connection may be simplified for explanatory purpose.

2. Equivalent Circuit

Equivalent circuit may be simplified for explanatory purpose.

3. Test Circuit

Test circuit may be simplified for explanatory purpose.

4. Timing Chart

Timing charts may be simplified for explanatory purposes.

IC Usage Considerations

Notes on handling of ICs

- (1) The absolute maximum ratings of a semiconductor device are a set of ratings that must not be exceeded, even for a moment. Do not exceed any of these ratings. Exceeding the rating(s) may cause device breakdown, damage or deterioration, and may result in injury by explosion or combustion.
- (2) Do not insert devices in the wrong orientation or incorrectly. Make sure that the positive and negative terminals of power supplies are connected properly. Otherwise, the current or power consumption may exceed the absolute maximum rating, and exceeding the rating(s) may cause device breakdown, damage or deterioration, and may result in injury by explosion or combustion. In addition, do not use any device inserted in the wrong orientation or incorrectly to which current is applied even just once.
- (3) Use an appropriate power supply fuse to ensure that a large current does not continuously flow in the case of overcurrent and/or IC failure. The IC will fully break down when used under conditions that exceed its absolute maximum ratings, when the wiring is routed improperly or when an abnormal pulse noise occurs from the wiring or load, causing a large current to continuously flow and the breakdown can lead to smoke or ignition. To minimize the effects of the flow of a large current in the case of breakdown, appropriate settings, such as fuse capacity, fusing time and insertion circuit location, are required.
- (4) If your design includes an inductive load such as a motor coil, incorporate a protection circuit into the design to prevent device malfunction or breakdown caused by the current resulting from the inrush current at power ON or the negative current resulting from the back electromotive force at power OFF. IC breakdown may cause injury, smoke or ignition. Use a stable power supply with ICs with built-in protection functions. If the power supply is unstable, the protection function may not operate, causing IC breakdown. IC breakdown may cause injury, smoke or ignition.
- (5) Carefully select external components (such as inputs and negative feedback capacitors) and load components (such as speakers), for example, power amp and regulator. If there is a large amount of leakage current such as from input or negative feedback condenser, the IC output DC voltage will increase. If this output voltage is connected to a speaker with low input withstand voltage, overcurrent or IC failure may cause smoke or ignition. (The overcurrent may cause smoke or ignition from the IC itself.) In particular, please pay attention when using a Bridge Tied Load (BTL) connection-type IC that inputs output DC voltage to a speaker directly.

Points to remember on handling of ICs

Heat Radiation Design

When using an IC with large current flow such as power amp, regulator or driver, design the device so that heat is appropriately radiated, in order not to exceed the specified junction temperature (Tj) at any time or under any condition. These ICs generate heat even during normal use. An inadequate IC heat radiation design can lead to decrease in IC life, deterioration of IC characteristics or IC breakdown. In addition, when designing the device, take into consideration the effect of IC heat radiation with peripheral components.

Back-EMF

When a motor rotates in the reverse direction, stops or slows abruptly, current flows back to the motor's power supply owing to the effect of back-EMF. If the current sink capability of the power supply is small, the device's motor power supply and output pins might be exposed to conditions beyond the absolute maximum ratings. To avoid this problem, take the effect of back-EMF into consideration in system design.

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